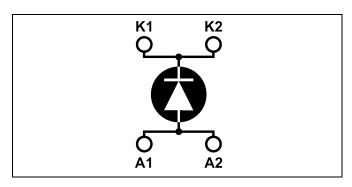


APTDF500U20G

Single diode Power Module

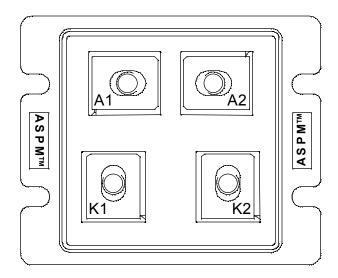
$$V_{CES} = 200V$$

 $I_{C} = 500A$ @ $Tc = 80$ °C



Application

- Anti-Parallel diode
 - Switchmode Power Supply
 - Inverters
- Snubber diode
- Uninterruptible Power Supply (UPS)
- Induction heating
- Welding equipment
- High speed rectifiers
- Electric vehicles



Features

- Ultra fast recovery times
- Soft recovery characteristics
- Very low stray inductance
- High blocking voltage
- High current
- Low leakage current

Benefits

- Low losses
- Low noise switching
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- RoHS Compliant

Absolute maximum ratings

| Symbol | Parameter | | | Max ratings | Unit |
|---------------------|---|------------------|---------------------|-------------|------|
| V_R | Maximum DC reverse Voltage | | | 200 | V |
| V_{RRM} | Maximum Peak Repetitive Reverse Voltage | | | 200 | v |
| т | Maximum Average Forward | Duta and - 500/ | $T_c = 25$ °C | 500 | |
| I _{F(A V)} | Current | Duty cycle = 50% | $T_c = 80$ °C | 500 | Α |
| I _{F(RMS)} | RMS Forward Current | | 850 | Λ | |
| I_{FSM} | Non-Repetitive Forward Surge Current | | $T_j = 25^{\circ}C$ | 5000 | |

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handing Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



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All ratings @ $T_i = 25^{\circ}$ C unless otherwise specified

Electrical Characteristics

| Symbol | Characteristic | Test Conditions | | Min | Typ | Max | Unit |
|------------------|---------------------------------|---|------------------------|-----|------|------|------|
| | Diode Forward Voltage | $I_F = 500 A$ | | | | 1.1 | |
| V_{F} | | $I_F = 1000A$ | | | 1.25 | | V |
| | | $I_F = 500 A$ | $T_{j} = 150^{\circ}C$ | | | 0.95 | |
| I_{RM} | Maximum Reverse Leakage Current | $V_R = 200V$ $T_j = 25^{\circ}C$ $T_j = 150^{\circ}C$ | $T_j = 25$ °C | | | 2500 | ^ |
| | | | | | 5000 | μΑ | |
| C_{T} | Junction Capacitance | $V_R = 200 V$ | | | 1000 | | pF |
| L_{S} | Series Inductance | Lead to Lead 5mm from Base | | | 30 | 40 | nН |

Dynamic Characteristics

| | Characteristic | Test Conditions | | Min | Typ | Max | Unit |
|-----------------------------|----------------------------------|---|----------------------------------|-----|------|-----|-------|
| t _{rr1} | Reverse Recovery Time | $I_F=1 A, V_R=30 V$ $di/dt = 15 A/\mu s$ | $T_j = 25$ °C | | 70 | | |
| t _{rr2} | | $I_F = 500 A$ | $T_j = 25$ °C | | 70 | | ns |
| t _{rr3} | | $V_R = 100 V$ di/dt= $800 A/\mu s$ | $T_j = 100^{\circ}C$ | | 150 | | |
| $\mathbf{t}_{\mathrm{fr}1}$ | - Forward Recovery Time | | $T_j = 25$ °C | | 250 | | ns |
| $t_{\rm fr2}$ | | | $T_{j} = 100^{\circ}C$ | | 250 | | 115 |
| I_{RRM1} | Reverse Recovery Current | | $T_j = 25^{\circ}C$ | | | 50 | Α |
| I_{RRM2} | | | $T_{j} = 100^{\circ}C$ | | | 120 | |
| Q_{rr1} | Reverse Recovery Charge | $I_F = 500 A$ $V_R = 100 V$ | $T_j = 25^{\circ}C$ | | 4.9 | | μC |
| Q _{rr2} | | di/dt=800A/μs | $T_{j} = 100^{\circ}C$ | | 22 | | μο |
| $V_{\mathrm{fr}1}$ | Forward Recovery Voltage | | $T_j = 25$ °C | | 15 | | V |
| V_{fr2} | | | $T_{j} = 100^{\circ}C$ | | 15 | | • |
| $d_{IM/dt}$ | Rate of Fall of Recovery Current | | $T_j = 25^{\circ}C$ | | 1200 | | A/μs |
| ⊶iivi/dt | Table 577 and 577 cooperations | | $T_{\rm j} = 100^{\circ}{\rm C}$ | | 1800 | | 11 μ5 |

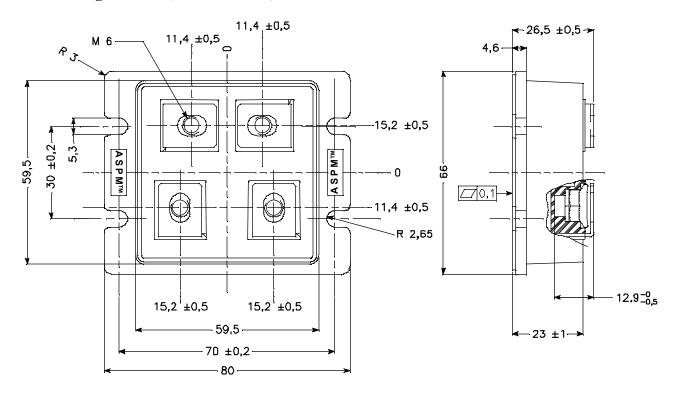
Thermal and package characteristics

| Symbol | Characteristic | | | Min | Typ | Max | Unit |
|----------------|--|---------------|----|------|-----|------|--------|
| R_{thJC} | Junction to Case Thermal Resistance | | | | | 0.08 | °C/W |
| $V_{\rm ISOL}$ | RMS Isolation Voltage, any terminal to case t=1 min, I isol<1mA, 50/60Hz | | | 2500 | | | V |
| T_{J} | Operating junction temperature range | | | -40 | | 150 | |
| T_{STG} | Storage Temperature Range | | | -40 | | 125 | °C |
| $T_{\rm C}$ | Operating Case Temperature | -40 | | 100 | | | |
| Torque | Mounting torque | To heatsink | M5 | 2.5 | | 3.5 | N.m |
| Torque | Wounting torque | For terminals | M6 | 3 | | 4 | 14.111 |
| Wt | Package Weight | | • | | • | 250 | g |



APTDF500U20G

LP4 Package outline (dimensions in mm)



Microsemi reserves the right to change, without notice, the specifications and information contained herein

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